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April 1st, 2010 Renesas Electronics Corporation

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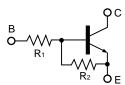
DATA SHEET

COMPOUND TRANSISTOR FB1 SERIES

ON-CHIP RESISTOR NPN SILICON EPITAXIAL TRANSISTOR FOR MID-SPEED SWITCHING

FEATURES

- Up to 0.7 A current drive available
- · On-chip bias resistor
- Low power consumption during drive
- <R> Package: 3-pin Mini Mold (SC-59)



FB1 SERIES LISTS

Products	Marking	R₁ (kΩ)	R₂ (kΩ)
FB1A4A	P30	_	10
FB1L2Q	P31	0.47	4.7
FB1A3M	P32	1.0	1.0
FB1F3P	P33	2.2	10
FB1J3P	P36	3.3	10
FB1L3N	P34	4.7	10
FB1A4M	P35	10	10

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	30	V
Collector to Emitter Voltage	VCEO	25	V
Emitter to Base Voltage	Vebo	10	V
Collector Current (DC)	IC(DC)	0.7	А
Collector Current (pulse) Note	IC(pulse)	1.0	А
Base Current (DC)	B(DC)	20	mA
Total Power Dissipation	P⊤	200	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

Note PW \leq 10 ms, Duty Cycle \leq 50%

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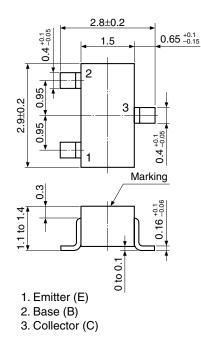
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PACKAGE DRAWING (Unit: mm)



ELECTRICAL CHARACTERISTICS (T_A = 25°C)

FB1A4A

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to Base Cut-off Current	Ісво	Vcb = 30 V, IE = 0 A			100	nA
DC Current Gain Note	hfe1	Vce = 2.0 V, Ic = 0.1 A	300			_
	hfe2	Vce = 2.0 V, Ic = 0.5 A	300			_
	hfe3	Vce = 2.0 V, Ic = 0.7 A	135			_
Collector Saturation Voltage Note	V _{CE(sat)}	Ic = 0.5 A, Iв = 5 mA		0.27	0.4	v
Low Level Input Voltage Note	VIL	Vcε = 5.0 V, Ic = 100 μA			0.3	v
Input Resistance	R1		_	_	_	Ω
Emitter to Base Resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, Duty Cycle \leq 2%

FB1L2Q

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to Base Cut-off Current	Ісво	Vcb = 30 V, IE = 0 A			100	nA
DC Current Gain Note	hfe1	Vce = 2.0 V, lc = 0.1 A	150	400		-
	hFE2	Vce = 2.0 V, Ic = 0.5 A	300	700		_
	h _{FE3}	Vce = 2.0 V, Ic = 0.7 A	135	600		_
Low Level Output Voltage Note	Vol	V _{IN} = 5.0 V, Ic = 0.5 A		0.2	0.3	V
Low Level Input Voltage Note	VIL	Vcε = 5.0 V, Ic = 100 μA		0.62	0.3	V
Input Resistance	R1		329	470	611	Ω
Emitter to Base Resistance	R ₂		3.29	4.7	6.11	kΩ

Note PW \leq 350 μ s, Duty Cycle \leq 2%

FB1A3M

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to Base Cut-off Current	Ісво	Vcb = 30 V, IE = 0 A			100	nA
DC Current Gain ^{Note}	hfe1	Vce = 2.0 V, lc = 0.1 A	80			_
	hFE2	Vce = 2.0 V, Ic = 0.5 A	100			_
	hfe3	Vce = 2.0 V, Ic = 0.7 A	135			_
Low Level Output Voltage Note	Vol	V _{IN} = 5.0 V, Ic = 0.5 A		0.3	0.4	V
Low Level Input Voltage Note	Vı∟	Vcε = 5.0 V, Ic = 100 μA			0.3	V
Input Resistance	R1		0.7	1.0	1.3	kΩ
Emitter to Base Resistance	R ₂		0.7	1.0	1.3	kΩ

Note PW \leq 350 μ s, Duty Cycle \leq 2%

FB1F3P

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to Base Cut-off Current	Ісво	Vcb = 30 V, IE = 0 A			100	nA
DC Current Gain Note	hfe1	Vce = 2.0 V, Ic = 0.1 A	300			_
	hfe2	Vce = 2.0 V, Ic = 0.5 A	300			_
	hfe3	Vce = 2.0 V, Ic = 0.7 A	135			_
Low Level Output Voltage Note	Vol	VIN = 5.0 V, Ic = 0.3 A			0.3	v
Low Level Input Voltage Note	VIL	Vcε = 5.0 V, Ic = 100 μA			0.3	v
Input Resistance	R1		1.54	2.2	2.86	kΩ
Emitter to Base Resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, Duty Cycle \leq 2%

FB1J3P

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to Base Cut-off Current	Ісво	Vcb = 30 V, IE = 0 A			100	nA
DC Current Gain Note	hfe1	Vce = 2.0 V, lc = 0.1 A	300	600		-
	hfe2	Vce = 2.0 V, Ic = 0.5 A	300	700		-
	hfe3	Vce = 2.0 V, Ic = 0.7 A	135	600		-
Low Level Output Voltage Note	Vol	V _{IN} = 5.0 V, Ic = 0.2 A		0.14	0.3	V
Low Level Input Voltage Note	Vı∟	Vcε = 5.0 V, lc = 100 μA		0.6	0.3	V
Input Resistance	R1		2.31	3.3	4.29	kΩ
Emitter to Base Resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, Duty Cycle \leq 2%

FB1L3N

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to Base Cut-off Current	Ісво	Vcb = 30 V, IE = 0 A			100	nA
DC Current Gain Note	hfe1	Vce = 2.0 V, Ic = 0.1 A	300			_
	hfe2	Vce = 2.0 V, Ic = 0.5 A	300			_
	hfe3	Vce = 2.0 V, Ic = 0.7 A	135			_
Low Level Output Voltage Note	Vol	VIN = 5.0 V, Ic = 0.2 A			0.3	V
Low Level Input Voltage Note	VIL	Vcε = 5.0 V, lc = 100 μA			0.3	V
Input Resistance	R₁		3.29	4.7	6.11	kΩ
Emitter to Base Resistance	R ₂		7	10	13	kΩ

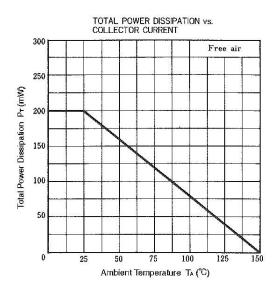
Note PW \leq 350 μ s, Duty Cycle \leq 2%

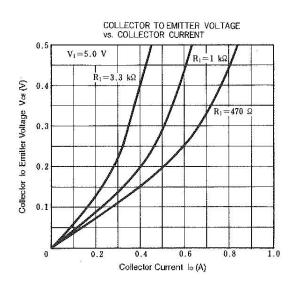
FB1A4M

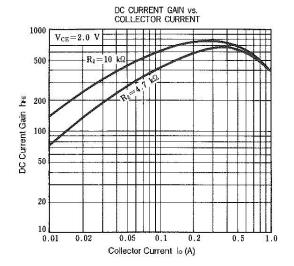
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to Base Cut-off Current	Ісво	Vcb = 30 V, IE = 0 A			100	nA
DC Current Gain Note	hfe1	Vce = 2.0 V, Ic = 0.1 A	300			_
	hfe2	Vce = 2.0 V, Ic = 0.5 A	300			_
	hfe3	Vce = 2.0 V, Ic = 0.7 A	135			_
Low Level Output Voltage Note	Vol	V _{IN} = 5.0 V, Ic = 0.2 A			0.3	v
Low Level Input Voltage Note	VIL	Vcε = 5.0 V, lc = 100 μA			0.3	v
Input Resistance	R1		7	10	13	kΩ
Emitter to Base Resistance	R2		7	10	13	kΩ

Note $PW \le 350 \ \mu s$, Duty Cycle $\le 2\%$

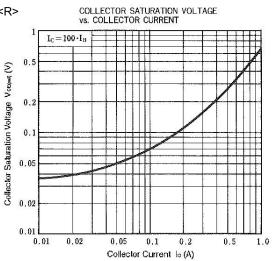
TYPICAL CHARACTERISTICS (T_A = 25°C)











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